

Description

The NTMFS5C468NL uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.

General Features

V_{DS} = 40V I_D =60 A

 $R_{DS(ON)} < 8.5 m\Omega @ V_{GS} = 10V$

Application

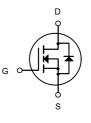
Battery protection

Load switch

Uninterruptible power supply







N-Channel MOSFET

Package Marking and Ordering Information

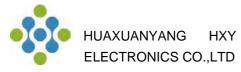
	U		
Product ID	Pack	Brand	Qty(PCS)
NTMFS5C468NL	DFN5X6-8L	HXY MOSFET	5000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units		
V _{DS}	Drain-Source Voltage	40	V		
Vgs	Gate-Source Voltage	±20	V		
I⊳@Tc=25°C	Continuous Drain Current, V _{GS} @ 10V ¹	Continuous Drain Current, V _{GS} @ 10V ¹ 60			
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	35	А		
Ідм	Pulsed Drain Current ²	105	А		
EAS	Single Pulse Avalanche Energy ³	48	mJ		
las	Avalanche Current	35	А		
P _D @T _C =25°C	Total Power Dissipation ⁴	39	W		
Тѕтс	Storage Temperature Range	orage Temperature Range -55 to 150			
TJ	Operating Junction Temperature Range	-55 to 150	°C		
Reja	R _{θJA} Thermal Resistance Junction-ambient (Steady 62 State) ¹		°C/W		
Rejc	Thermal Resistance Junction-Case ¹	3.2	°C/W		

NTMFS5C468NL

N-Channel Enhancement Mode MOSFET



Electrical Characteristics (T = 25 , unless otherwise noted)

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit	
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40			V	
Rds(on)		V _{GS} =10V , I _D =10A		7	8.5	mΩ	
	Static Drain-Source On-Resistance ²	V _{GS} =4.5V , I _D =5A		10	15		
VGS(th)	Gate Threshold Voltage	Threshold Voltage V _{GS} =V _{DS} , I _D =250uA		1.7	3	V	
IDSS	Drain-Source Leakage Current	V _{DS} =32V , V _{GS} =0V , T _J =25°C			1	– uA	
		V _{DS} =32V , V _{GS} =0V , T _J =55°C			5		
Igss	Gate-Source Leakage Current	V _{GS=} ±20V , V _{DS} =0V			±100	nA	
gfs	Forward Transconductance	V _{DS} =10V , I _D =5A		27		S	
Qg	Total Gate Charge (4.5V)			20			
Qgs	Gate-Source Charge			5.8		nC	
Qgd	Gate-Drain Charge	_		9.5			
Td(on)	Turn-On Delay Time			15.2			
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V		8.8		ns	
Td(off)	Turn-Off Delay Time	$-R_{G}=3.3 \Omega$		74			
T _f	Fall Time	I _D =1A		7			
Ciss	Input Capacitance			690			
Coss	Output Capacitance			193		pF	
Crss	Reverse Transfer Capacitance	-		38			
ls	Continuous Source Current ^{1,5}	$V_G=V_D=0V$, Force Current			70	A	
Vsd	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1	V	

Note :

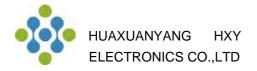
1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

2.The data tested by pulsed , pulse width \leqq 300us , duty cycle \leqq 2%

3. The EAS data shows Max. rating . The test condition is $V_{DD}=25V$, $V_{GS}=10V$, L=0.1 mH, $I_{AS}=47$ A

4.The power dissipation is limited by 150 $^\circ\!\mathrm{C}$ junction temperature

5.The data is theoretically the same as I_{D} and I_{DM} , in real applications , should be limited by total power dissipation.



NTMFS5C468NL N-Channel Enhancement Mode MOSFET

Typical Characteristics

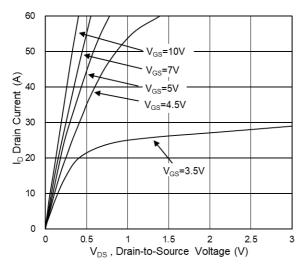


Fig.1 Typical Output Characteristics

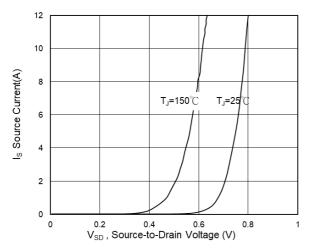


Fig.3 Source Drain Forward Characteristics

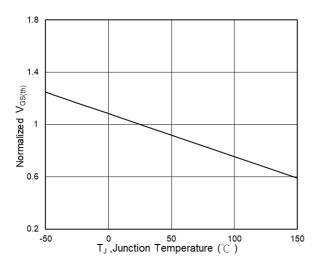


Fig.5 Normalized $V_{GS(th)}\,vs\,T_J$

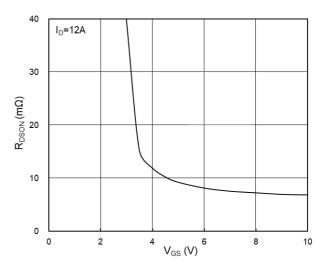


Fig.2 On-Resistance vs G-S Voltage

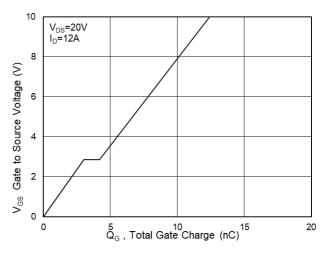


Fig.4 Gate-Charge Characteristics

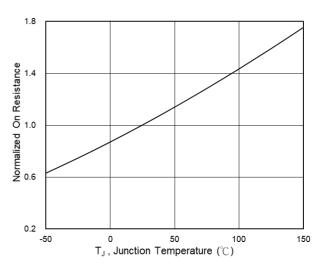
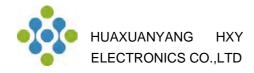
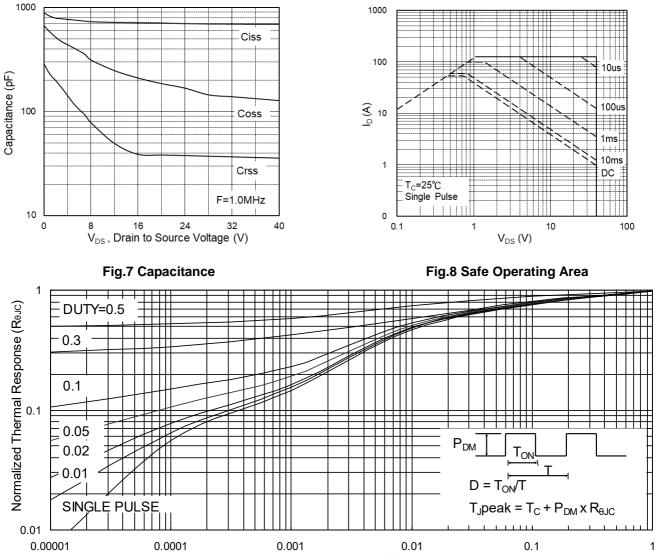


Fig.6 Normalized R_{DSON} vs T_J





t, Pulse Width (s)



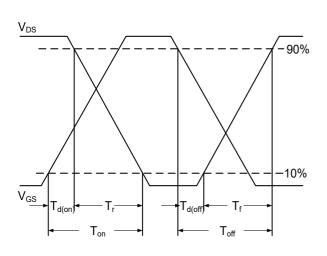


Fig.10 Switching Time Waveform

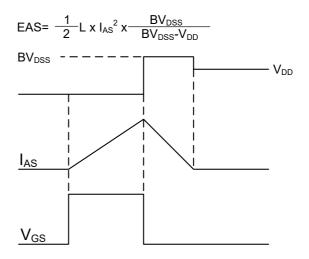
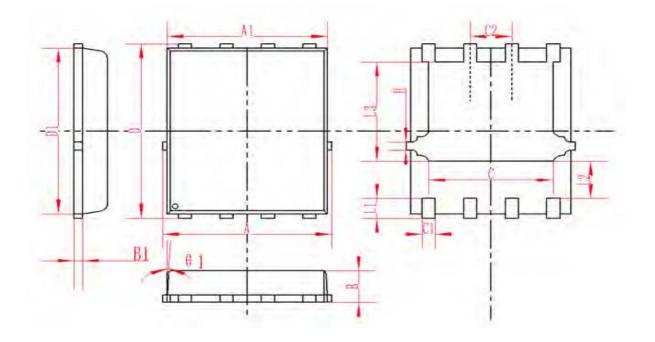


Fig.11 Unclamped Inductive Waveform



DFN5X6-8L Package Information



SYMBOL	MM		INCH			
	MIN	NOM	MAX	MIN	NOM	MAX
А	4.95	5	5.05	0.195	0.197	0.199
A1	4.82	4.9	4.98	0.190	0.193	0.196
D	5.98	6	6.02	0.235	0.236	0.237
D1	5.67	5.75	5.83	0.223	0.226	0.230
В	0.9	0.95	1	0.035	0.037	0.039
B1	0.254REF		0.010REF			
С	3.95	4	4.05	0.156	0.157	0.159
C1	0.35	0.4	0.45	0.014	0.016	0.018
C2		1.27TYP			0.5TYP	
θ1	8°	10°	12°	8°	10°	12°
L1	0.63	0.64	0.65	0.025	0.025	0.026
L2	1.2	1.3	1.4	0.047	0.051	0.055
L3	3.415	3.42	3.425	0.134	0.135	0.135
Н	0.24	0.25	0.26	0.009	0.010	0.010



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